Supporting information

Glycerol-assistedGrainModulationinFemtosecond-Laser-inducedPhotochemicalSynthesis of Patterned ZnO Nanomaterials

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Supporting Figures:



Figure S1. Chemical reactions of components during the precursor preparation and

FsLDW.



Figure S2. Transmittance (a) and reflectance (b) of the soda-lime glass substrate.



Figure S3. SEM images of ZnO microstructures fabricated with different laser power

(a) (d) ranging from 60 mW to 120 mW when the scanning speed is 10 μ m s⁻¹ and scanning speeds (b) (e) ranging from 10 μ m s⁻¹ to 100 μ m s⁻¹ when laser power is 120 mW; (c) SEM images of ZnO microstructures fabricated with laser power of 120 mW and scanning speed of 120 μ m s⁻¹.



Figure S4. The optical image of the FLDW results on the flexible substrate (PI).



Figure S5. XPS spectra of the (a) Zn 2p and (b) O 1s of ZnO fabricated by femtosecond

laser direct writing with and without thermal annealing, respectively.



Figure S6. XRD curves of laser-fabricated zinc oxide synthesized by FLDW and annealing at 550°C for 2 hours correspond to the indexation of the diffraction peaks for zinc oxide.



Figure S7. Grain size distribution of the FsLDW products with 20 vol.% glycerol (a)

and without (b).



Figure S8. The absorption spectrum of the precursor solution with or without glycerol.

M _r	Molecular formula	M _r	Molecular formula
155	Zn(OH) ₂	309	(CH ₃ COO)Zn ⁺ Zn ⁺ (CH ₃ COO)
184	Zn(CH ₃ COO) ₂	341	(CH ₃ COO)Zn ⁺ Zn ⁺ (CH ₃ COO) ОН НО
199	Zn(CH ₃ COO)(OH)	369	(CH ₃ COO)Zn ⁺ Zn ⁺ (CH ₃ COO)
215	(C ₃ H ₈ O ₂)…► Zn ²⁺ ◄…(C ₃ H ₈ O ₂)	383	(CH ₃ COO)—Zn-O-Zn-(CH ₃ COO)
241	Zn(CH ₃ COO) ₂	397	$(C_3H_8O_2)\cdots = Z_n^{2^+} Z_n^{2^+} \cdots (C_3H_8O_2)$
Notes	$= \frac{H_2C}{H_2C} OH $	C ₃ H ₈ O ₂)	$\Rightarrow = \begin{array}{c} H_3C \\ O \\ CH_2 \\ CH_2 \\ OH \\ \cdots \end{array}$

Figure S9. Substances contained in the analysis results of liquid chromatography-mass



Figure S10. The results of liquid chromatography-mass spectrometry of the precursor

solution with or without glycerol. (a) and (b) are the analysis result by the cation mode.



(c) and (d) are the analysis result by the anion mode.

Figure S11. The results of liquid chromatography-mass spectrometry of the molecules with a mass-to-charge ratio greater than 400. (a) and (b) are the analysis results of the cation mode. (c) and (d) are the analysis results by the anion mode.



Figure S12. The switching ratio of ZnO UV detector with varying glycerol

concentrations

Supporting Table:

Material	On/Off ratio/ light power intensity	Responsi vity (A/W)	I _{dark} (A)/ Bias voltage	Fabrication Method	Ref.
rGO/ZnO	~2 (20.03 mW/cm ²)	3.24	3.9×10 ⁻⁶ /1V	Selective FsLDW	1
ZnO NRs	7.5×10 ⁵ (20 mW/cm ²)	2.81	3.5×10 ⁻⁹ /10V	Wet screen printing	2
ZnO NWs	300 (0.43 mW/cm ²)	4×10 ⁴	$10^{-8} \sim 10^{-9} / 5 V$	Fs laser 3D assembly	3
ZnO NWs	250 (2.5 μW/cm ²)	2×10 ⁷	~10 ⁻⁸ /1.5V	Contact printing	4
ZnO/PEG	2.8×10 ⁵ (10.15 mW/cm ²)	1.77	2.57×10 ⁻¹⁰ /3V	Drop casting	5
ZnO NWs	2.5×10^{3} (2 µW/cm ²)	55	10 ⁻⁹ /5V	spray coating	6
ZnO granular NWs	~10 ⁶ (77.5 µW/cm ²)	7.5×10 ⁶	2×10 ⁻¹¹ /1V	Near-field electrospinning	7
Patterned ZnO NPs	2.8×10 ⁵ (2 mW/cm ²)	2.78×10 ²	<10 ⁻¹¹ /10V	Glycerin- assisted FsLDW	Our Work

Table S1 Summary the photoresponse of UV photodetectors based on ZnO materials

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